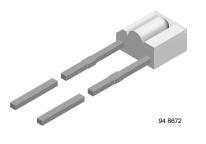
TSSS2600

www.vishay.com

Vishay Semiconductors

Infrared Emitting Diode, 950 nm, GaAs



DESCRIPTION

TSSS2600 is an infrared, 950 nm emitting diode in GaAs technology, molded in a miniature, clear plastic package with side view lens.

FEATURES

- Package type: leaded
- · Package form: side view
- Dimensions (L x W x H in mm): 3.6 x 2.2 x 5
- Peak wavelength: $\lambda_p = 950 \text{ nm}$
- High reliability
- · High radiant power
- High radiant intensity
- Angle of half intensity: $\varphi = \pm 25^{\circ}$, horizontal
- · Low forward voltage
- · Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Package matched with detector TEST2600
- · Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

· Infrared source in miniature light barriers or reflective sensor systems with short transmission distances and low forward voltage requirements. Matching with silicon PIN photodiodes or phototransistors (e.g. TEST2600)

PRODUCT SUMMARY

| COMPONENT | l _e (mW/sr) | φ (deg) | λ _p (nm) | tr (ns) |
|-----------|------------------------|---------|---------------------|---------|
| TSSS2600 | 2.6 | ± 25 | 950 | 800 |

Note

Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION | | | | |
|----------------------|-----------|------------------------------|--------------|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | |
| TSSS2600 | Bulk | MOQ: 5000 pcs, 5000 pcs/bulk | Side view | |

Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|----------------------------------|-------------------|---------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Reverse voltage | | V _R | 5 | V | |
| Forward current | | l _F | 100 | mA | |
| Peak forward current | $t_p/T = 0.5, t_p = 100 \ \mu s$ | I _{FM} | 200 | mA | |
| Surge forward current | t _p = 100 μs | I _{FSM} | 2.0 | А | |
| Power dissipation | | Pv | 170 | mW | |
| Junction temperature | | Tj | 100 | °C | |
| Operating temperature range | | T _{amb} | - 40 to + 100 | °C | |
| Storage temperature range | | T _{stg} | - 40 to + 100 | °C | |
| Soldering temperature | $t \le 5$ s, 2 mm from case | T _{sd} | 260 | °C | |
| Thermal resistance junction/ambient | Leads not soldered | R _{thJA} | 450 | K/W | |



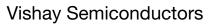
RoHS

COMPLIANT

GREEN (5-2008)**

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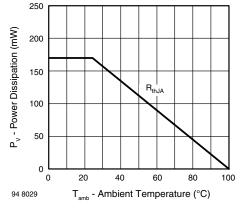


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

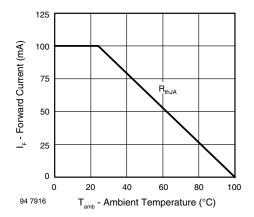


Fig. 1 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|---|------------------|------|-------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | I _F = 100 mA, t _p = 20 ms | V _F | | 1.25 | 1.6 | V |
| | I _F = 1.5 A, t _p = 100 μs | V _F | | 2.2 | | V |
| Temperature coefficient of V_F | I _F = 100 mA | TK _{VF} | | - 1.3 | | mV/K |
| Reverse current | V _R = 5 V | I _R | | | 100 | μA |
| Junction capacitance | $V_{R} = 0 V, f = 1 MHz, E = 0$ | Cj | | 30 | | pF |
| Radiant intensity | I _F = 100 mA, t _p = 20 ms | l _e | 1 | 2.6 | 3 | mW/sr |
| | I _F = 1.5 A, t _p = 100 μs | l _e | | 25 | | mW/sr |
| Radiant power | I _F = 100 mA, t _p = 20 ms | фе | | 20 | | mW |
| Temperature coefficient of ϕ_{e} | I _F = 100 mA | ΤKφ _e | | - 0.8 | | %/K |
| Angle of half intensity | horizontal | φ1 | | ± 25 | | deg |
| | vertical | φ2 | | ± 60 | | deg |
| Peak wavelength | I _F = 100 mA | λρ | | 950 | | nm |
| Spectral bandwidth | I _F = 100 mA | Δλ | | 50 | | nm |
| Temperature coefficient of λ_p | I _F = 100 mA | ΤΚλρ | | 0.2 | | nm/K |
| Rise time | I _F = 100 mA | t _r | | 800 | | ns |
| | I _F = 1.5 A | t _r | | 400 | | ns |
| Fall time | I _F = 100 mA | t _f | | 800 | | ns |
| | I _F = 1.5 A | t _f | | 400 | | ns |
| Virtual source diameter | | d | | 2 | | mm |



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

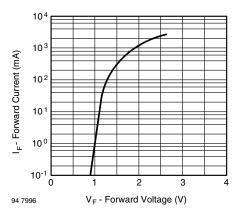


Fig. 2 - Pulse Forward Current vs. Forward Voltage

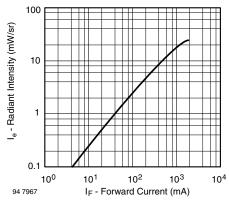


Fig. 3 - Radiant Intensity vs. Forward Current

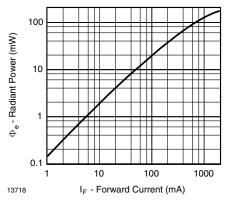


Fig. 4 - Radiant Power vs. Forward Current

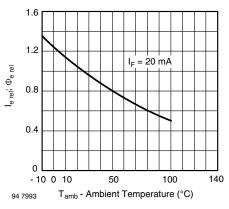


Fig. 5 - Relative Radiant Intensity/Power vs. Ambient Temperature

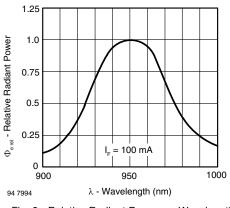


Fig. 6 - Relative Radiant Power vs. Wavelength

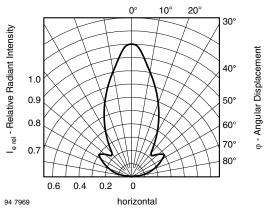


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

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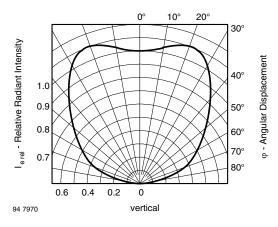
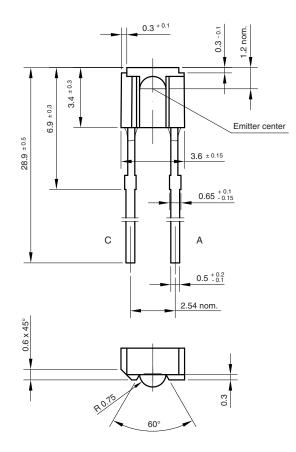
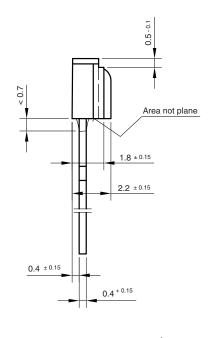


Fig. 2 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters







according to DIN specifications

Drawing-No.: 6.544-5241.01-4 Issue: 3; 18.04.96 95 11488

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